This GIDEP PCN is to announce specifications change with the datasheet parameters for the following International Rectifier Part No. Note that this change is related to part specification only, and not due to a die physical change.

IRHLF7S7214 [2N7610T2]
250V, N-Channel, TID Hardened MOSFET in a TO-205AF package

ELECTRICAL CHARACTERISTICS @ Tj = 25°C, Post Total Dose Irradiation

Add $R_{DS(on)}$ [Static Drain-to-Source On-State Resistance] for TO-3 test in Table 1
-Test Parameter: Max Limit for up to 300K Rads(Si) = 0.88Ω.
-Test Conditions: $V_{gs} = 4.5V$, $I_D = 2.1A$.

Reference Datasheet PD-97833